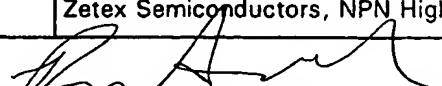




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FORM PTO-1449 INFORMATION DISCLOSURE STATEMENT				ATTY DOCKET NO. 870-003-162		SERIAL NO. 10/ 722,835	
				APPLICANTS: HAHN et al.			
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UNITED STATES PATENT DOCUMENTS							
EXAM. INITIAL		DOCUMENT NUMBER	DATE	INVENTOR/ASSIGNEE	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
Rm		5,610,486	MAR. '97	LI/SGS-THOMSON	318	439	
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Rm	DE	696 07 880-T2	SEP. '96	LI			= USP 5,610,486
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